



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. .... 10/636,038  
Filing Date ..... August 6, 2003  
Confirmation No. .... 9972  
Inventor ..... Gurtej S. Sandhu  
Assignee ..... Micron Technology, Inc.  
Group Art Unit ..... 1762  
Examiner ..... Eric B. Fuller  
Attorney's Docket No. .... MI22-2194  
Customer No. .... 021567  
Title: Methods of Forming Material on a Substrate, and Method of Forming a  
Field Effect Transistor Gate Oxide on a Substrate

**RESPONSE TO MARCH 23, 2006 FINAL OFFICE ACTION**  
**PRELIMINARY AMENDMENT TO ACCOMPANY RCE FILING**

To: Mail Stop RCE  
Commissioner for Patents  
P. O. Box 1450  
Alexandria, VA 22313-1450

**VIA U.S. EXPRESS MAIL**

From: Mark S. Matkin (Tel. 509-624-4276; Fax 509-838-3424)  
Wells St. John P.S.  
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Responsive to the Final Office Action dated March 23, 2006, Applicant  
amends and remarks as follows:

**AMENDMENTS**